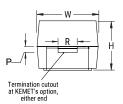


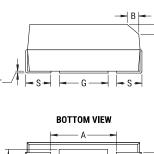
T498D475K035ATE1K0

T498, Tantalum, MnO2 Tantalum, High Temperature, 4.7 uF, 10%, 35 VDC, SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200, N/A, 1 Ohms, 7343, 3.1 mm, 1.3 mm

CATHODE (-) END VIEW



ANODE (+) END VIEW



SIDE VIEW



Click here for the 3D model.

General Information	
Series	T498
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Hi-Temp, 150C, Auto, AEC-Q200
Features	Automotive, 150C
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
AEC-Q200	Yes
Typical Component Weight	446.84 mg
Shelf Life	156 Weeks
MSL	1

Dimensions	
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
н	2.8mm +/-0.3mm
т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
A	3.8mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	0.9mm REF
R	1mm REF
х	0.1mm +/-0.1mm REF

Specifications	
Capacitance	4.7 uF
Tolerance	10%
Voltage DC	35 VDC (85C), 28 VDC (125C), 23.45 VDC (150C)
Temperature Range	-55/+150°C
Rated Temperature	85°C
Dissipation Factor	4.5% 120Hz 25C
Failure Rate	N/A
ESR	1000 mOhms (100kHz 25C)
Ripple Current	387 mA (rms, 100kHz 25C), 348.3 mA (rms, 85C), 116.1 mA (rms, 150C)
Leakage Current	1.6 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.